

ASMT-QxBD-Axxxx

Super 0.5 W Power PLCC-4 Surface Mount LED Indicator



A Broadcom Limited Company

Data Sheet



Description

The Super 0.5 W Power PLCC-4 SMT LED is an extension of Power PLCC-4 SMT LEDs. The package can be driven at high current due to its superior package design. The product is able to dissipate the heat more efficiently compared to the Power PLCC-4 SMT LEDs. These LEDs produce higher light output with better flux performance compared to the Power PLCC-4 SMT LED.

The Super 0.5 W Power PLCC-4 SMT LEDs are designed for higher reliability, better performance, and operate under a wide range of environmental conditions. The performance characteristics of these new mid-power LEDs make them uniquely suitable for use in harsh conditions such as in automotive applications, and in electronics signs and signals.

To facilitate easy pick and place assembly, the LEDs are packed in EIA-compliant tape and reel. Every reel is shipped in single intensity and color bin (except for red), to provide close uniformity.

Super 0.5 W Power PLCC-4 SMT LED is available in red and amber colors.

Features

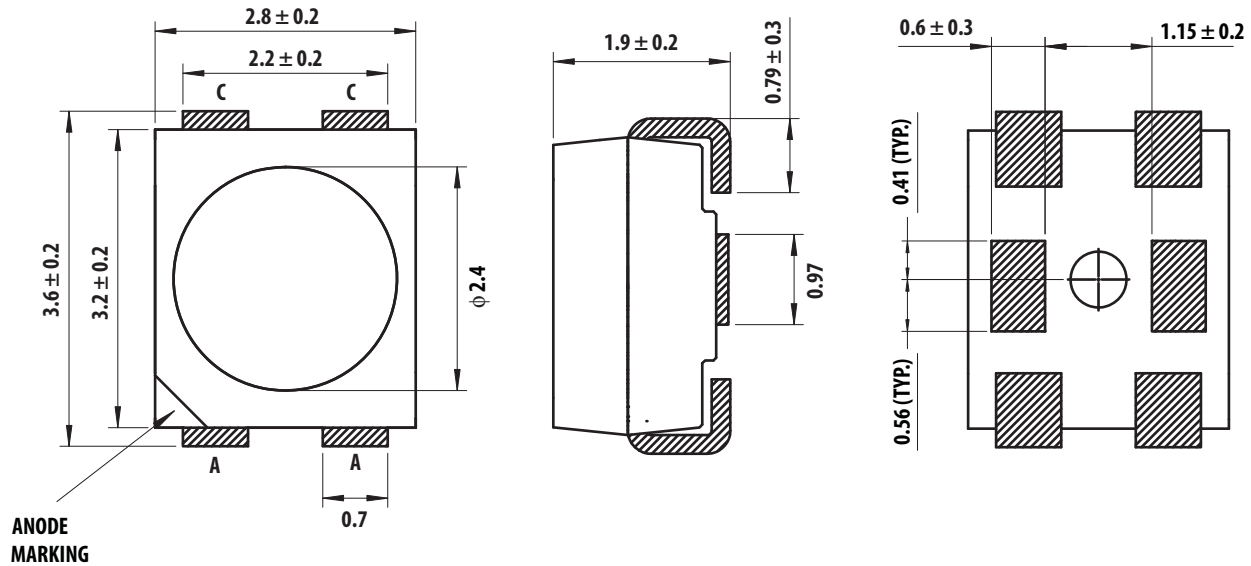
- Industry Standard PLCC 4 platform (3.2 mm × 2.8 mm × 1.9 mm)
- High reliability package with enhanced silicone resin encapsulation
- High intensity brightness with optimum flux performance using AlInGaP chip technologies
- Available in Red and Amber colors
- High optical efficiency
- Available in 8mm carrier tape & 7 inch reel
- Low Thermal Resistance 60°C/W
- Super wide viewing angle at 120°
- Longer life time with minimum degradation due to enhanced Silicone resin material
- JEDEC MSL 2

Applications

- Exterior automotive
 - Turn signals
 - Side repeaters
 - CHSML
 - Rear combination lamp
 - Side markers
 - Truck clearance lamp
- Electronic signs and signals
 - Channel lettering
 - Contour lighting
 - Indoor variable message sign
- Office automation, home appliances, industrial equipment
 - Front panel backlighting
 - Push button backlighting
 - Display backlighting

CAUTION: ASMT-QxBD-Axxxx LEDs are Class 2 ESD sensitive. Please observe appropriate precautions during handling and processing. Refer to Avago Application Note AN-1142 for additional details.

Package Drawing



Note:

1. All Dimensions in millimeters.
2. Lead Polarity as shown in Figure 12.
3. Terminal Finish: Ag plating
4. Encapsulation material: Silicone resin

Figure 1. Package Drawing

Table 1. Device Selection Guide

| Color | Part Number | Luminous Flux, $\Phi_V^{[1]}$ (lm) | | | Test Current (mA) | Dice Technology |
|------------|-----------------|------------------------------------|----------------|----------------|-------------------|-----------------|
| | | Min. Flux (lm) | Typ. Flux (lm) | Max. Flux (lm) | | |
| Amber | ASMT-QABD-AEF0E | 11.5 | 16.5 | 19.5 | 150 | AlInGaP |
| Amber | ASMT-QABD-AEFJE | 11.5 | - | 19.5 | 150 | AlInGaP |
| Red Orange | ASMT-QHBD-AEFBE | 11.5 | - | 19.5 | 150 | AlInGaP |
| Red Orange | ASMT-QHBD-AFH0E | 15.0 | 17.5 | 33.0 | 150 | AlInGaP |
| Red Orange | ASMT-QHBD-AFG0E | 15.0 | - | 25.5 | 150 | AlInGaP |
| Red | ASMT-QRBD-AEF0E | 11.5 | 16.5 | 19.5 | 150 | AlInGaP |

Notes:

1. Φ_V is the total luminous flux output as measured with an integrating sphere at mono pulse condition.
2. Flux tolerance is $\pm 12\%$

Part Numbering System

ASMT-Q X₁ B D - A X₂ X₃ X₄ X₅

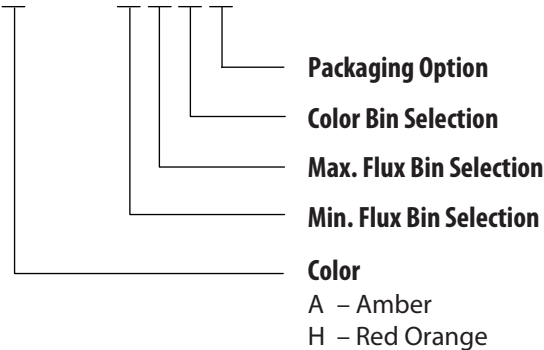


Table 2. Absolute Maximum Ratings ($T_A = 25\text{ }^{\circ}\text{C}$)

| Parameters | ASMT-QxBD-Axxxx |
|--|---|
| DC Forward Current ^[1] | 150 mA |
| Peak Forward Current ^[2] | 300 mA |
| Power Dissipation | 450 mW |
| Reverse Voltage, V_R @ 100 μA | 5 V |
| Junction Temperature | 125 $^{\circ}\text{C}$ |
| Operating Temperature | -40 $^{\circ}\text{C}$ to +120 $^{\circ}\text{C}$ |
| Storage Temperature | -40 $^{\circ}\text{C}$ to +120 $^{\circ}\text{C}$ |

Notes:

1. Derate Linearly as shown in Figure 6.
2. Duty Factor = 10%, Frequency = 1 kHz

Table 3. Optical Characteristics ($T_J = 25\text{ }^{\circ}\text{C}$)

| Color | Part Number | Dice Technology | Peak Wavelength | Dominant Wavelength | Viewing Angle | Luminous Efficiency η_e | Total Flux / Luminous Intensity |
|------------|-----------------|-----------------|--------------------------------------|---|--|------------------------------|------------------------------------|
| | | | λ_{PEAK} (nm) Typ. | λ_D ^[1] (nm) Typ. | $2\theta_{1/2}$ ^[2] (Degrees) Typ. | (lm/W) Typ. | Φ_V (lm) / I_V (cd) Typ. |
| Amber | ASMT-QABD-Axx0E | AlInGaP | 596.2 | 593.1 | 120 | 44 | 2.5 |
| Red Orange | ASMT-QHBD-Axx0E | AlInGaP | 624.1 | 616.1 | 120 | 47 | 2.5 |
| Red | ASMT-QRBD-Axx0E | AlInGaP | 629.7 | 621.1 | 120 | 44 | 2.5 |

Notes:

1. The dominant wavelength, λ_D , is derived from the CIE Chromaticity diagram and represents the color of the device.
2. $\theta_{1/2}$ is the off-axis angle where the luminous intensity is $1/2$ the peak intensity.

Table 4. Electrical Characteristics ($T_J = 25^{\circ}\text{C}$)

| Part Number | Forward Voltage V_F (V) @ $I_F = 150\text{ mA}$ | | | Thermal Resistance $R_{\theta J-P}$ ($^{\circ}\text{C/W}$) |
|-----------------|---|------|------|---|
| | Min. | Typ. | Max. | |
| ASMT-QABD-AxxxE | 2.05 | 2.30 | 2.95 | 60 |
| ASMT-QHBD-AxxxE | 2.05 | 2.50 | 2.95 | 60 |
| ASMT-QRBD-AxxxE | 2.05 | 2.50 | 2.95 | 60 |

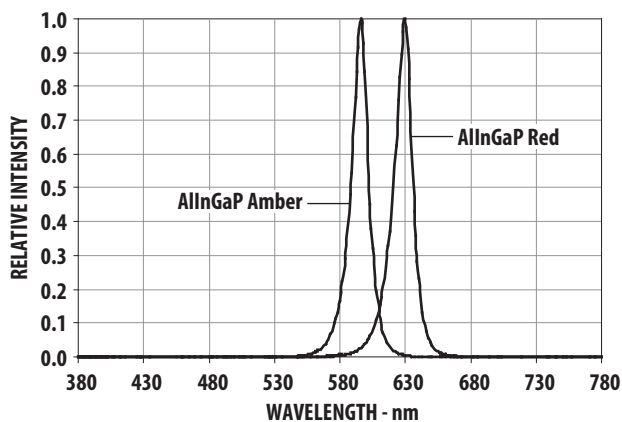


Figure 2. Relative Intensity Vs. Wavelength

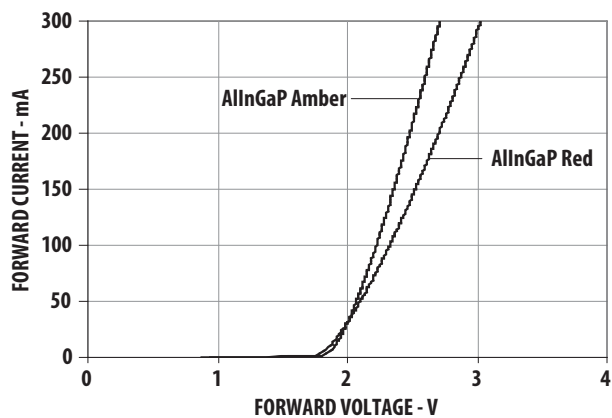


Figure 3. Forward Current Vs. Forward Voltage.

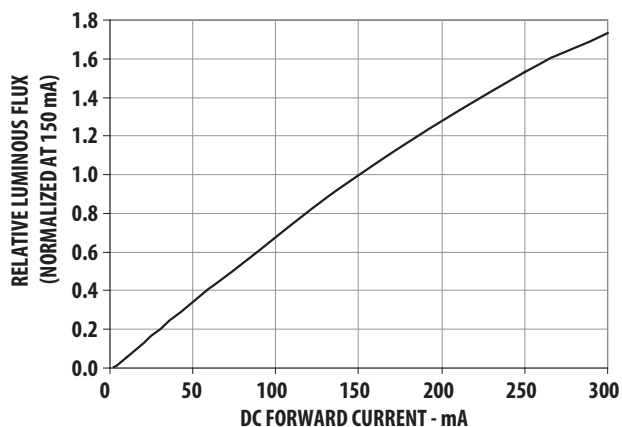


Figure 4. Relative Intensity Vs. Forward Current

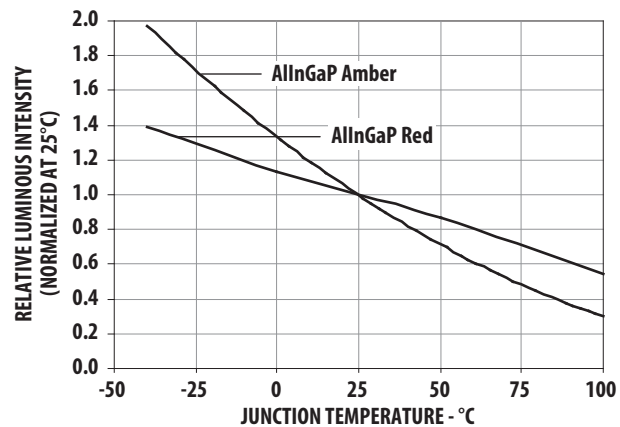


Figure 5. Relative Intensity Vs. Temperature

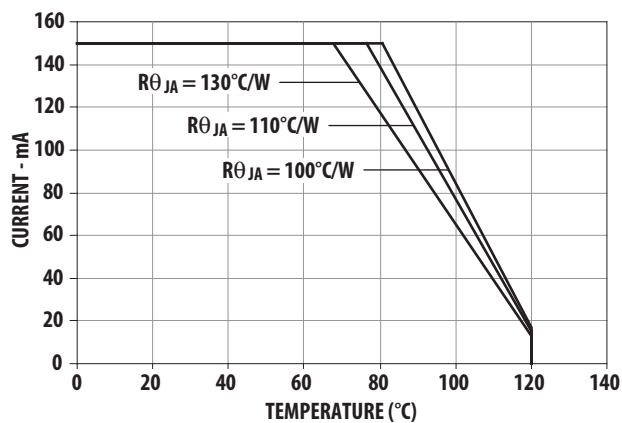


Figure 6a. Maximum Forward Current Vs. Ambient Temperature.
Derated based on $T_{JMAX} = 125^{\circ}\text{C}$, $R_{\theta JA} = 130^{\circ}\text{C/W}$, 110°C/W & 100°C/W .

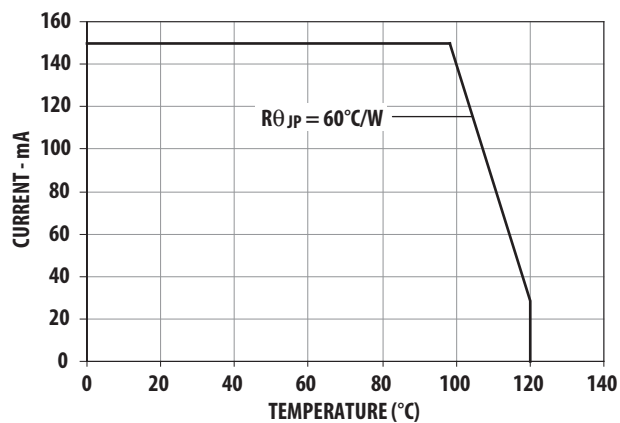


Figure 6b. Maximum Forward Current Vs. Solder Point Temperature.
Derated based on $T_{JMAX} = 125^{\circ}\text{C}$, $R_{\theta JP} = 60^{\circ}\text{C/W}$.

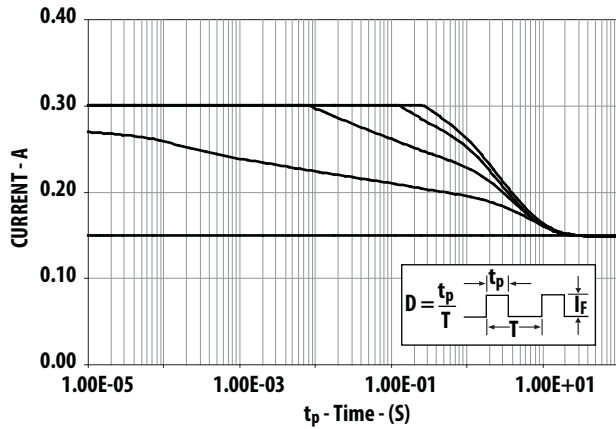


Figure 7a. Maximum Pulse Current vs. Ambient Temperature.
Derated based on $T_A = 25^\circ\text{C}$, $R_{\Theta JA} = 110^\circ\text{C/W}$.

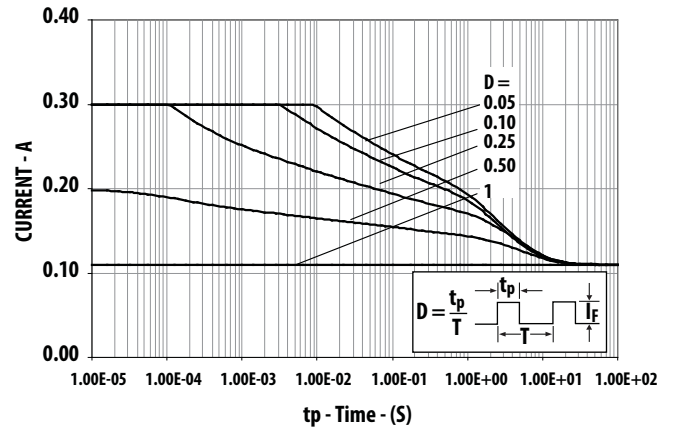


Figure 7b. Maximum Pulse Current vs. Ambient Temperature.
Derated based on $T_A = 85^\circ\text{C}$, $R_{\Theta JA} = 110^\circ\text{C/W}$.

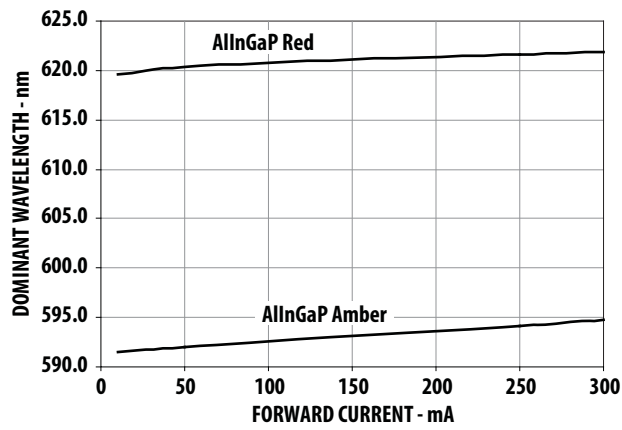


Figure 8. Dominant Wavelength Vs. Forward Current - AlInGaP Devices.

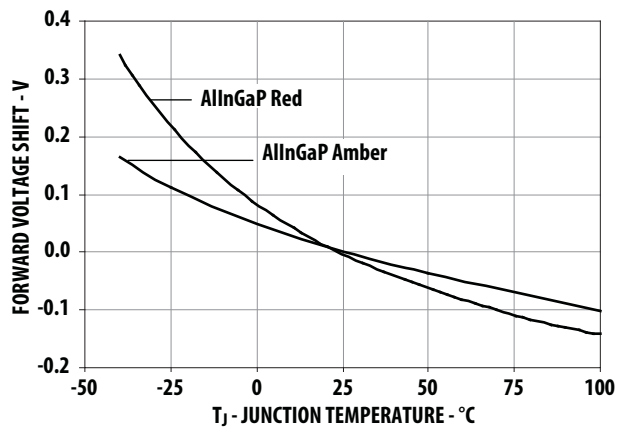


Figure 9. Forward Voltage Shift Vs. Temperature.

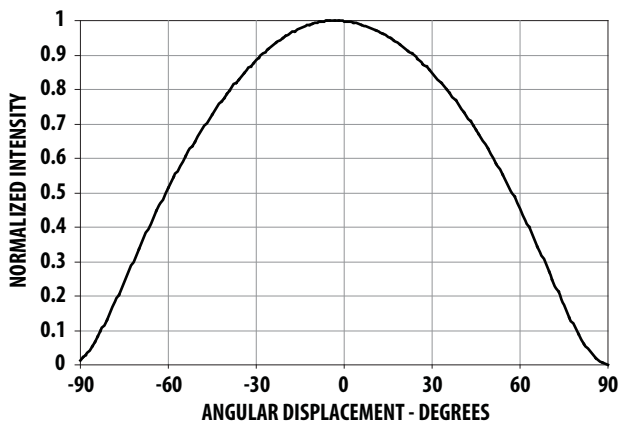


Figure 10. Radiation Pattern

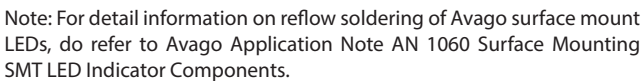


Figure 1 illustrates the PCB layout and cross-section of the LED package. The top left shows a top-down view of the package with cathode (C) and anode (A) markings. The top right shows a cross-section of the package with dimensions: 2.4, 0.6, 0.9 x 6, 1.3 x 6, 1.1, 4.6, 0.4, and 0.3. The bottom right shows a cross-section of the package with dimensions: 0.4, 0.3, 1.1, 1.3 x 6, 4.6, and 0.6. The bottom left shows a cross-section of the package with dimensions: 0.4, 0.3, 1.1, 1.3 x 6, 4.6, and 0.6.

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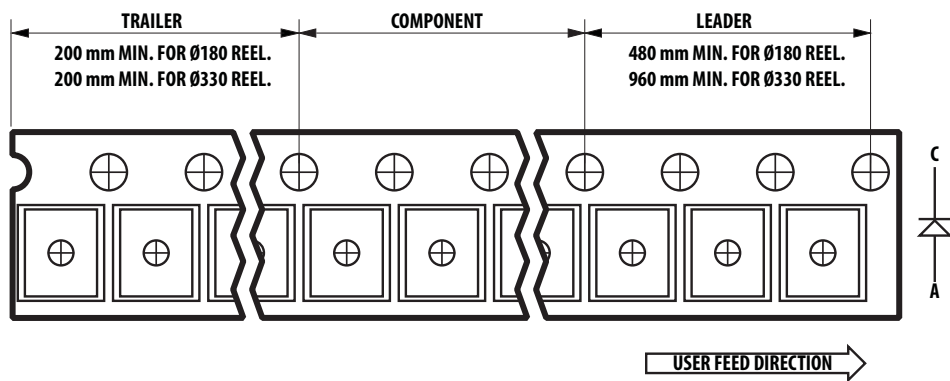


Figure 13. Tape Leader and Trailer Dimensions

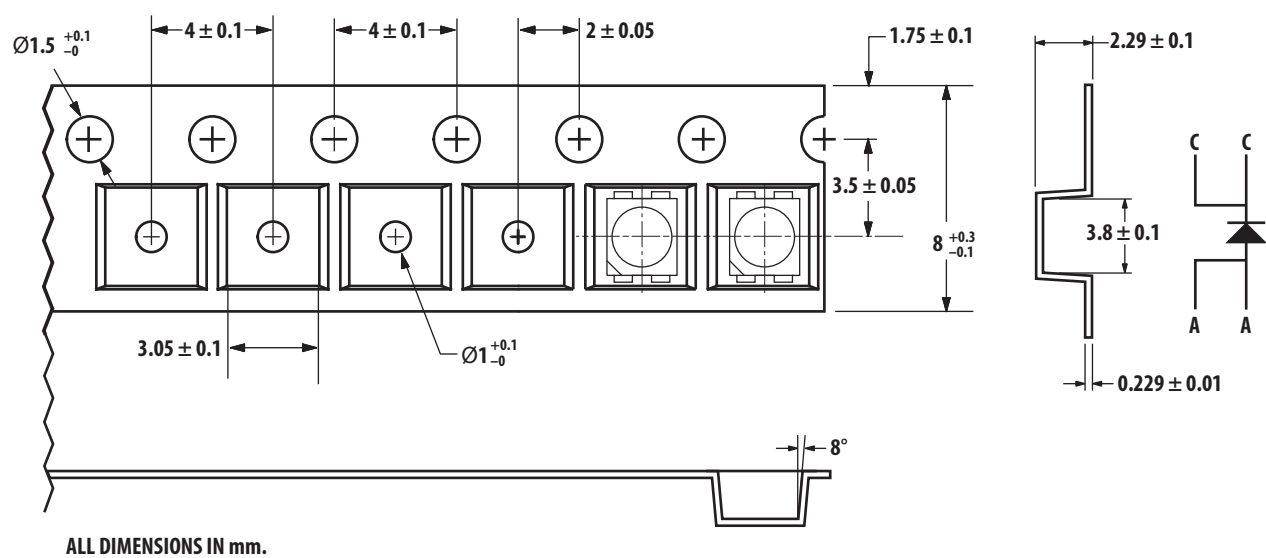


Figure 14. Tape Dimensions

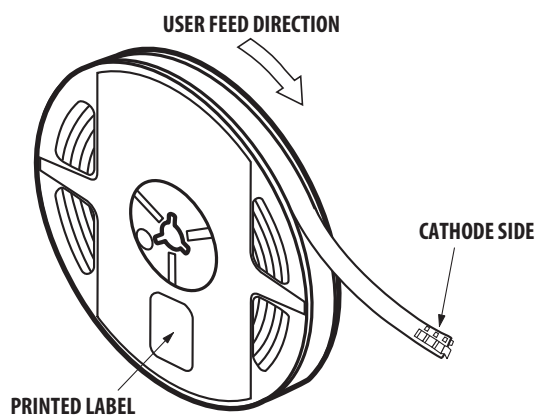


Figure 15. Reeling Orientation

Device Color (X₁)

| | |
|---|------------|
| A | Amber |
| H | Red Orange |
| R | Red |

Flux Bin Select (X₂X₃)

Individual reel will contain parts from one bin only

| | |
|----------------|--------------|
| X ₂ | Min Flux Bin |
| X ₃ | Max Flux Bin |

Flux Bin Limits

| Bin ID | Min. (lm) | Max. (lm) |
|--------|-----------|-----------|
| 0 | 3.30 | 4.30 |
| A | 4.30 | 5.50 |
| B | 5.50 | 7.00 |
| C | 7.00 | 9.00 |
| D | 9.00 | 11.50 |
| E | 11.50 | 15.00 |
| F | 15.00 | 19.50 |
| G | 19.50 | 25.50 |
| H | 25.50 | 33.00 |
| J | 33.00 | 43.00 |
| K | 43.00 | 56.00 |
| L | 56.00 | 73.00 |

Tolerance of each bin limit = ± 12%

Color Bin Select (X₄)

Individual reel will contain parts from one full bin only.

| X ₄ | |
|----------------|-----------------------|
| 0 | Full Distribution |
| A | 1 and 2 only |
| B | 2 and 3 only |
| C | 3 and 4 only |
| D | 4 and 5 only |
| E | 5 and 6 only |
| G | 1, 2 and 3 only |
| H | 2, 3 and 4 only |
| J | 3, 4 and 5 only |
| K | 4, 5 and 6 only |
| M | 1, 2, 3 and 4 only |
| N | 2, 3, 4 and 5 only |
| P | 3, 4, 5 and 6 only |
| R | 1, 2, 3, 4 and 5 only |
| S | 2, 3, 4, 5 and 6 only |
| Z | Special Color Bin |

Color Bin Limits

| Amber/Yellow | Min. (nm) | Max. (nm) |
|--------------|-----------|-----------|
| 2 | 583.0 | 586.0 |
| 3 | 586.0 | 589.0 |
| 4 | 589.0 | 592.0 |
| 5 | 592.0 | 595.0 |
| 6 | 595.0 | 598.0 |

| Red Orange | Min. (nm) | Max. (nm) |
|------------|-----------|-----------|
| 1 | 611.0 | 616.0 |
| 2 | 616.0 | 620.0 |
| 3 | 620.0 | 625.0 |

| Red | Min. (nm) | Max. (nm) |
|-------------------|-----------|-----------|
| Full Distribution | 620.0 | 635.0 |

Tolerance of each bin limit = ± 1 nm

V_F Binning

| Bin | Min. | Max. |
|-----|------|------|
| 2B | 2.05 | 2.20 |
| 2C | 2.20 | 2.35 |
| 2D | 2.35 | 2.50 |
| 2E | 2.50 | 2.65 |
| 2F | 2.65 | 2.80 |
| 2G | 2.80 | 2.95 |

Tolerance of each bin = ± 0.1 V

Packaging Option (X₅)

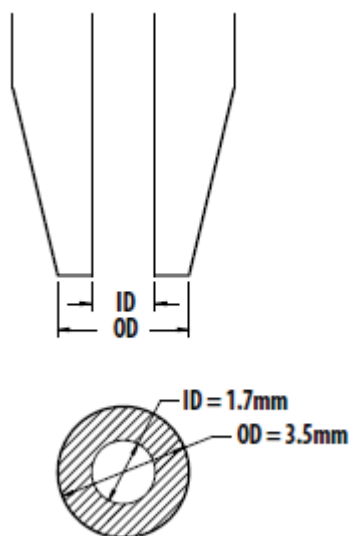
| Option | Test Current | Package Type | Reel Size |
|--------|--------------|--------------|-----------|
| E | 150 mA | Top Mount | 7 inch |

Precautionary Notes

1. Handling precautions

The encapsulation material of the LED is made of silicone for better product reliability. Compared to epoxy encapsulant that is hard and brittle, silicone is softer and flexible. Special handling precautions must be observed during assembly of silicone encapsulated LED products. Failure to comply might lead to damage and premature failure of the LED. Refer to Application Note AN5288, *Silicone Encapsulation for LED: Advantages and Handling Precautions* for more information.

- Do not poke sharp objects into the silicone encapsulant. Sharp objects, such as tweezers or syringes, might apply excessive force or even pierce through the silicone and induce failures to the LED die or wire bond.
- Do not touch the silicone encapsulant. Uncontrolled force acting on the silicone encapsulant might result in excessive stress on the wire bond. Hold the LED only by the body.
- Do not stack assembled PCBs together. Use an appropriate rack to hold the PCBs.
- The surface of the silicone material attracts dust and dirt easier than epoxy due to its surface tackiness. To remove foreign particles on the surface of silicone, use a cotton bud with isopropyl alcohol (IPA). During cleaning, rub the surface gently without putting much pressure on the silicone. Ultrasonic cleaning is not recommended.
- For automated pick and place, Avago has tested the following nozzle size to work with this LED. However, due to the possibility of variations in other parameters, such as pick and place, machine maker/model, and other settings of the machine, verify that the selected nozzle will not cause damage to the LED.



2. Handling of moisture sensitive device

This product has a Moisture Sensitive Level 2 rating per JEDEC J-STD-020. Refer to Avago Application Note AN5305, *Handling of Moisture Sensitive Surface Mount Devices*, for additional details and a review of proper handling procedures.

- Before use
 - An unopened moisture barrier bag (MBB) can be stored at $<40^{\circ}\text{C}/90\%\text{RH}$ for 12 months. If the actual shelf life has exceeded 12 months and the humidity indicator card (HIC) indicates that baking is not required, then it is safe to reflow the LEDs per the original MSL rating.
 - Do not open the MBB prior to assembly (e.g., for IQC).
- Control after opening the MBB
 - Read the HIC immediately upon opening of the MBB.
 - Keep the LEDs at $<30^{\circ}\text{C}/60\%\text{RH}$ at all times. All high temperature-related processes, including soldering, curing, or rework, must be completed within 1 year.
- Control for unfinished reel
 - Store unused LEDs in a sealed MBB with desiccant or desiccator at $<5\%\text{RH}$.
- Control of assembled boards
 - If the PCB soldered with the LEDs will be subjected to other high-temperature processes, the PCB must be stored in a sealed MBB with desiccant or desiccator at $<5\%\text{RH}$ to ensure that all LEDs have not exceeded their floor life of 1 year.
- Baking is required if:
 - The HIC indicator is not BROWN at 10% and is AZURE at 5%.
 - The LEDs are exposed to conditions of $>30^{\circ}\text{C}/60\%\text{RH}$ at any time.
 - The LED floor life exceeded 168 hrs.

The recommended baking condition is: $60^{\circ}\text{C} \pm 5^{\circ}\text{C}$ for 20 hrs.

Baking should only be done once.
- Storage
 - The soldering terminals of these Avago LEDs are silver plated. If the LEDs are exposed in ambient environment for too long, the silver plating might become oxidized, which affects its solderability performance. As such, keep unused LEDs in a sealed MBB with desiccant or in desiccator at $<5\%\text{RH}$.

3. Application precautions

- a. The drive current of the LED must not exceed the maximum allowable limit across temperature as stated in the data sheet. Constant current driving is recommended to ensure consistent performance.
- b. LEDs exhibit slightly different characteristics at different drive currents, which might result in larger variation in their performance (i.e. intensity, wavelength, and forward voltage). Set the application current as close as possible to the test current to minimize these variations.
- d. Do not use the LED in the vicinity of material with sulfur content, in environments with high gaseous sulfur compound and corrosive elements. Examples of materials that may contain sulfur are rubber gasket, room temperature vulcanizing (RTV) silicone rubber, rubber gloves etc. Prolonged exposure to such environments may affect the optical characteristics and product life.
- e. Avoid rapid change in ambient temperature, especially in high-humidity environments, because this causes condensation on the LED.
- f. Although the LED is rated as IPx6 according to IEC60529: Degree of protection provided by the enclosure, the test condition may not represent actual exposure during application. If the LED is intended to be used in outdoor or harsh environments, protect the LED against damages caused by rain water, dust, oil, corrosive gases, external mechanical stress, etc.

4. Thermal management

Optical, electrical, and reliability characteristics of the LED are affected by temperature. The junction temperature (T_J) of the LED must be kept below allowable limits at all times. T_J can be calculated as below:

$$T_J = T_A + R_{\theta J-A} \times I_F \times V_{Fmax}$$

where;

T_A = ambient temperature [$^{\circ}\text{C}$]

$R_{\theta J-A}$ = thermal resistance from LED junction to ambient [$^{\circ}\text{C}/\text{W}$]

I_F = forward current [A]

V_{Fmax} = maximum forward voltage [V]

The complication of using this formula lies in T_A and $R_{\theta J-A}$. Actual T_A is sometimes subjective and hard to determine. $R_{\theta J-A}$ varies from system to system depending on the design and is usually not known.

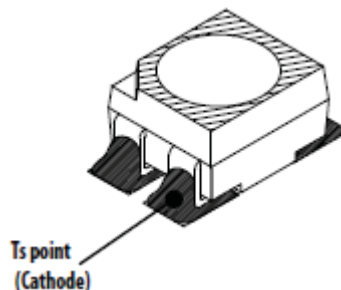
Another way of calculating T_J is by using solder point temperature T_S as follows:

$$T_J = T_S + R_{\theta J-S} \times I_F \times V_{Fmax}$$

where;

T_S = LED solder point temperature as shown in the following illustration [$^{\circ}\text{C}$]

$R_{\theta J-S}$ = thermal resistance from junction to solder point [$^{\circ}\text{C}/\text{W}$]



T_S can be measured easily by mounting a thermocouple on the soldering joint as shown in the preceding illustration, while $R_{\theta J-S}$ is provided in the data sheet. Verify the T_S of the LED in the final product to ensure that the LEDs are operated within all maximum ratings as stated in the data sheet.

For product information and a complete list of distributors, please go to our web site: www.avagotech.com

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